

# **Preliminary**

15 A

## PJP15NA50A / PJF15NA50A

Current

## 600V N-Channel MOSFET

500 V

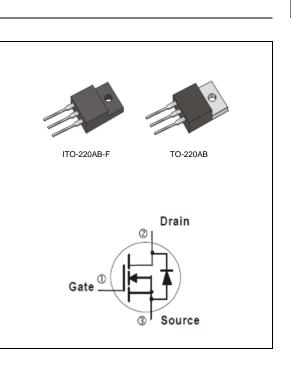
Voltage

### Features

- R<sub>DS(ON)</sub>, V<sub>GS</sub>@10V,I<sub>D</sub>@7.5A<0.43Ω
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

#### **Mechanical Data**

- Case: TO-220AB, ITO-220AB-F Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- TO-220AB Approx. Weight : 0.067 ounces, 1.89 grams
- ITO-220AB-F Approx. Weight : 0.068 ounces, 2 grams



## Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER		SYMBOL	TO-220AB	ITO-220AB-F	UNITS	
Drain-Source Voltage		V <sub>DS</sub>	500	V		
Gate-Source Voltage		$V_{GS}$	<u>+</u> 30	V		
Continuous Drain Current		I <sub>D</sub>	15	А		
Pulsed Drain Current		I <sub>DM</sub>	60	А		
Single Pulse Avalanche Energy (Note 1)		E <sub>AS</sub>	500	mJ		
Power Dissipation	T <sub>C</sub> =25°C	P <sub>D</sub>	195	52	W	
	Derate above 25°C		1.56	0.42	W/°C	
Operating Junction and Storage Temperature Range		T <sub>J</sub> ,T <sub>STG</sub>	-55~150		°C	
Typical Thermal resistance						
- Junction to Case		$R_{ extsf{ heta}JC}$	0.64	2.4	°C/W	
- Junction to Ambient		$R_{ extsf{ heta}JA}$	62.5	120		
Limited only By Maximum Junction Temperature						



## **Electrical Characteristics** ( $T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V,I <sub>D</sub> =250uA	500	-	-	V
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =250uA	2	-	4	V
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V,I <sub>D</sub> =7.5A	-	0.37	0.43	Ω
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =500V,V <sub>GS</sub> =0V	-	-	1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 30V,V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =15A,V <sub>GS</sub> =0V	-	0.87	1.4	V
Dynamic (Note 4)						
Total Gate Charge	Qg		-	36	-	nC
Gate-Source Charge	$Q_{gs}$	$V_{DS}$ =400V, $I_{D}$ =15A, $V_{GS}$ =10V <sup>(Note 2,3)</sup>	-	10	-	
Gate-Drain Charge	$Q_gd$	V <sub>GS</sub> =10V	-	11	-	
Input Capacitance	Ciss		-	1475	-	
Output Capacitance	Coss V <sub>DS</sub> =25V, V <sub>GS</sub> =0V,		-	196	-	pF
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	8	-	
Turn-On Delay Time	td <sub>(on)</sub>		-	15	-	ns
Turn-On Rise Time	t <sub>r</sub>	V <sub>DD</sub> =250V, I <sub>D</sub> =15A, R <sub>G</sub> =25Ω <sub>(Note 2,3)</sub>	-	31	-	
Turn-Off Delay Time	td <sub>(off)</sub>		-	38	-	
Turn-Off Fall Time	t <sub>f</sub>		-	30	-	
Drain-Source Diode						
Maximum Continuous Drain-Source			-	-	15	А
Diode Forward Current	I <sub>S</sub>					
Aximum Pulsed Drain-Source			-	-	60	А
Reverse Recovery Charge	Qrr	dI <sub>F</sub> / dt=100A/us <sup>(Note 2)</sup>	-	6.2	-	uC

NOTES :

1. L=10mH, I<sub>AS</sub>=10A, V<sub>DD</sub>=50V, R<sub>G</sub>=25 ohm, Starting T<sub>J</sub>=25°C

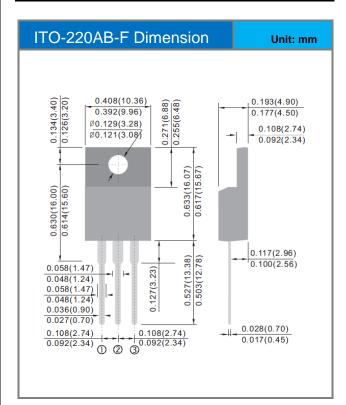
2. Pulse width</200us, Duty cycle<2%

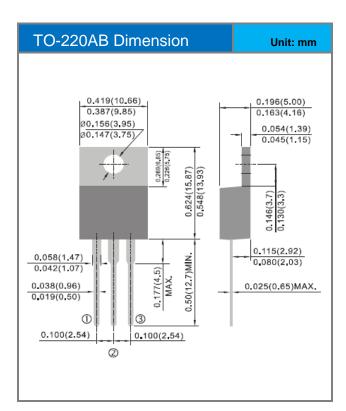
3. Essentially independent of operating temperature typical characteristics.

4. Guaranteed by design, not subject to production testing



### **Packaging Information**







### PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJP15NA50A_T0_00001	TO-220AB	50pcs / Tube	15NA50A	Halogen free
PJF15NA50A_T0_00001	ITO-220AB-F	50pcs / Tube	15NA50A	Halogen free



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